

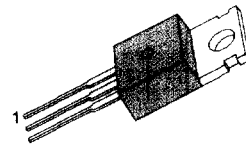
LOW FREQUENCY POWER AMPLIFIER

- Complement to KSB834

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V_{CB0}	60	V
Collector-Emitter Voltage	V_{CE0}	60	V
Emitter-Base Voltage	V_{EB0}	7	V
Collector Current	I_C	3	A
Base Current	I_B	0.3	A
Collector Dissipation ($T_C=25^\circ\text{C}$)	P_C	30	W
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 ~ 150	$^\circ\text{C}$

TO-220



1. Base 2. Collector 3. Emitter

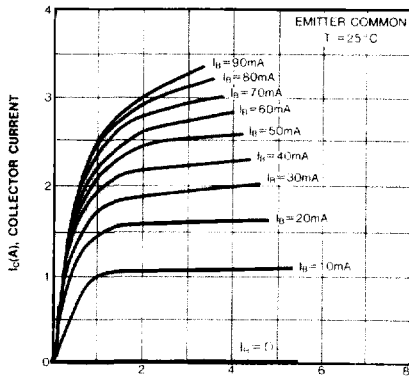
ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cutoff Current	I_{CB0}	$V_{CB} = 60\text{V}, I_E = 0$			100	μA
Emitter Cutoff Current	I_{EB0}	$V_{EB} = 7\text{V}, I_C = 0$			100	μA
Collector-Emitter Breakdown Voltage	BV_{CE0}	$I_C = 50\text{mA}, I_B = 0$	60			V
DC Current Gain	h_{FE1}	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$	60		300	
	h_{FE2}	$V_{CE} = 5\text{V}, I_C = 3\text{A}$	20			
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 3\text{A}, I_B = 0.3\text{A}$		0.4	1	V
Base Emitter On Voltage	$V_{BE(on)}$	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$		0.7	1	V
Current Gain Bandwidth Product	f_T	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$		3		MHz
Collector Output Capacitance	C_{OB}	$V_{CB} = 10\text{V}, I_E = 0, f = 1\text{MHz}$		70		pF
Turn on Time	t_{ON}	$I_{B1} = -I_{B2} = 0.2\text{A}$		0.8		μs
Storage Time	t_{STG}	$V_{CC} = 30\text{V}$		1.5		μs
Fall Time	t_F			0.8		μs

 $h_{FE}(1)$ CLASSIFICATION

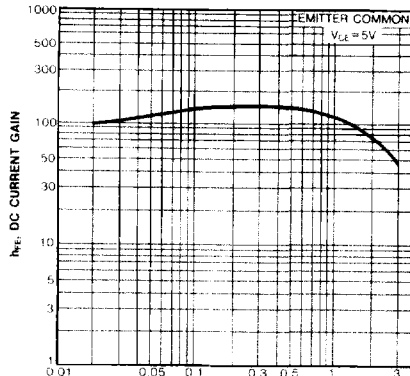
Classification	O	Y	G
$h_{FE}(1)$	60 - 120	100 - 200	150 - 300

STATIC CHARACTERISTIC



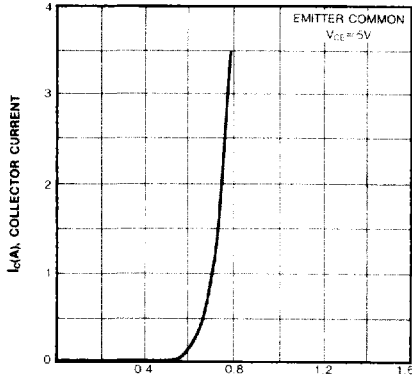
V_{CE} (V), COLLECTOR-EMITTER VOLTAGE

DC CURRENT GAIN



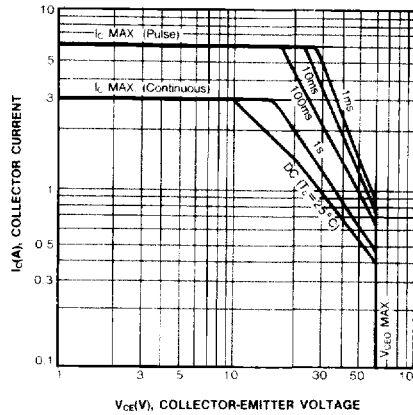
I_C (A), COLLECTOR CURRENT

BASE-EMITTER ON VOLTAGE



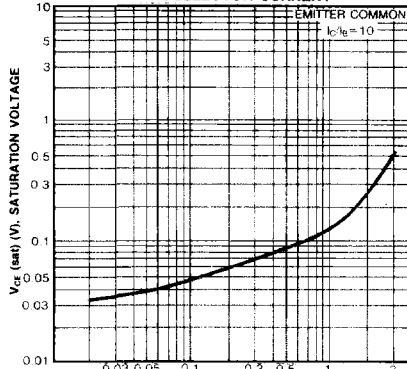
V_{BE} (V), BASE-EMITTER VOLTAGE

SAFE OPERATING AREA



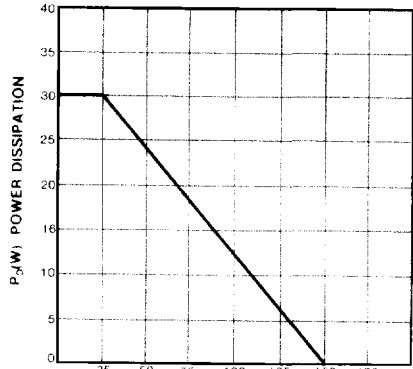
V_{CE} (V), COLLECTOR-EMITTER VOLTAGE

COLLECTOR-EMITTER SATURATION VOLTAGE vs COLLECTOR CURRENT



I_C (A), COLLECTOR CURRENT

POWER DERATING



T_{c1} (°C), CASE TEMPERATURE